

ALT5020

High Efficiency UMTS E800 (Band 20) LTE Linear PAM

ADVANCED PRODUCT INFORMATION - Rev 0.0

FEATURES

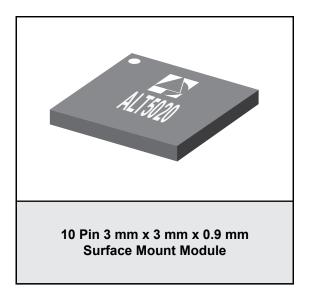
- LTE Compliant
- High Efficiency (LTE waveform):
 - 42% @ Pout = +27.7 dBm
- · Optimized for SMPS Supply
- Low Leakage Current in Shutdown Mode: <5 μA
- Internal Voltage Regulator
- Integrated "daisy chainable" directional coupler with CPLIN and CPLOUT Ports
- Optimized for a 50 Ω System
- Internal DC blocks on IN/OUT RF ports
- 1.8 V Control Logic
- RoHS Compliant Package, 260 °C MSL-3

APPLICATIONS

- · Wireless Handsets and Data Devices for:
 - LTE (B20)

PRODUCT DESCRIPTION

The ALT5020 PA is designed to provide highly linear output for LTE handsets and data devices with high efficiency at high power mode. This ANADIGICS PA can be used with an external switch mode power supply (SMPS) to improve its efficiency and reduce current consumption further at high and low output powers. The device is manufactured on an advanced InGaP HBT MMIC technology offering state-of-theart reliability, temperature stability, and ruggedness. There are three selectable bias modes that optimize efficiency for different output power levels, and a shutdown mode with low leakage current, which increases handset talk and standby time. The selfcontained 3 mm x 3 mm x 0.9 mm surface mount package incorporates matching networks optimized for output power, efficiency, and linearity in a 50 Ω system.



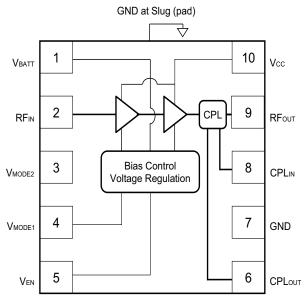


Figure 1: Block Diagram

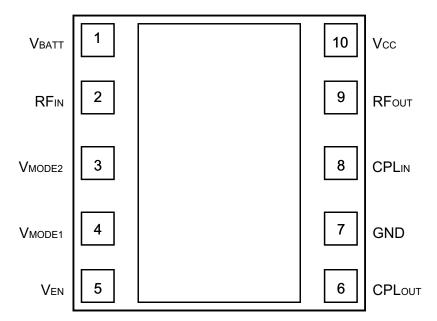


Figure 2: Pinout (X-ray Top View)

Table 1: Pin Description

PIN	NAME	DESCRIPTION	
1	V_{BATT}	Battery Voltage	
2	RFℕ	RF Input	
3	V _{MODE2}	Mode Control Voltage 2	
4	V _{MODE1}	Mode Control Voltage 1	
5	V_{EN}	PA Enable Voltage	
6	СРLоит	Coupler Output	
7	GND	Ground	
8	CPLIN	Coupler Input	
9	RFоит	RF Output	
10	Vcc	Supply Voltage	

ELECTRICAL CHARACTERISTICS

Table 2: Absolute Minimum and Maximum Ratings

PARAMETER	MIN	TYP	MAX	UNIT
RF Input (Pin)	-	0	10	dBm
Vcc	0	3.4	5	V
Vватт	0	3.4	6	V
Control Voltage (Venable, Vmode)	0	1.8	3.5	V
Storage Temperature (Tstorage)	-40	25	150	°C

Functional operation to the specified performance is not implied under these conditions. Operation of any single parameter in excess of the absolute ratings may cause permanent damage. No damage occurs if one parameter is set at the limit while all other parameters are set within normal operating ranges.

Table 3: Operating Ranges

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS	
Operating Frequency (f)	832	-	862	MHz	UMTS Band 20	
Supply Voltage (Vcc)	+0.6	+3.4	+4.4	V	Ро∪т <u>≤</u> +27.7 dВm	
Battery Voltage (VBATT)	+3.1	+3.4	+4.4	٧	Роит <u><</u> +27.7 dBm	
Enable Voltage (VENABLE)	+1.35 0	+1.8 0	+3.1 +0.5	V	PA "on" PA "shut down"	
Mode Control Voltage (VMODE1)	+1.35 0	+1.8 0	+3.1 +0.5	V	Low Bias Mode High Bias Mode	
RF Output Power (Pout) (1, 2, 3) LTE, HPM LTE, LPM	26.9 -	27.7 16	- -	dBm	TS 36.101 Rel 8 for LTE	
Case Temperature (Tc)	-30	-	+90	°C		

The device may be operated safely over these conditions; however, parametric performance is guaranteed only over the conditions defined in the electrical specifications.

Notes:

- (1) For operation at Vcc = +3.1 V, Pouτ is derated by 0.8 dB.
- (2) For operation at 105 °C, Pouτ is derated by 1.0 dB.
- (3) LTE waveform characteristics up to 20 MHz QPSK, 18 RB's.

Table 4: Electrical Specifications - LTE Operation (RB = 12, START = 0, QPSK) (Tc = +25 °C, VBATT = +3.4 V, VEN = +1.8 V, 50 Ω system, unless otherwise specified)

(Tc = +25 °C, VBATT = +3.4 V, VEN = +1.8 V, 50 Ω system, unless otherwise specified)								
PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS			
PARAIVIETER	IVIIIN	ITP		UNII	Роит	V cc	V _{MODE1}	VMODE2
Gain	26.5 18 14	30 22 17	33 25 21	dB	+27.7 dBm +16 dBm +7 dBm	3.4 V 1.4 V 0.7 V	0 V 1.8 V 1.8 V	0 V 0 V 1.8 V
ACLR E-UTRA (1) at ± 10 MHz offset	- - -	-38 -38 -40	-34 -34 -34	dBc	+27.7 dBm +16 dBm +7 dBm	3.4 V 1.4 V 0.7 V	0 V 1.8 V 1.8 V	0 V 0 V 1.8 V
ACLR1 UTRA (1) at ± 7.5 MHz offset	- - -	-39 -39 -40	-36 -36 -36	dBc	+27.7 dBm +16 dBm +7 dBm	3.4 V 1.4 V 0.7 V	0 V 1.8 V 1.8 V	0 V 0 V 1.8 V
ACLR2 UTRA (1) at ± 12.5 MHz offset	- - -	<-60 <-60 <-60	-40 -40 -40	dBc	+27.7 dBm +16 dBm +7 dBm	3.4 V 1.4 V 0.7 V	0 V 1.8 V 1.8 V	0 V 0 V 1.8 V
Efficiency (1)	33 - -	38 22 13	- - -	%	+27.7 dBm +16 dBm +7 dBm	3.4 V 1.4 V 0.7 V	0 V 1.8 V 1.8 V	0 V 0 V 1.8 V
Quiescent Current (Icq) Low Bias Mode	-	25	-	mA	through Vcc	oin, Vmodi	_{=1,2} = +1.8	3 V
Mode Control Current	-	0.05	0.1	mA	through VMOE	ь pin, Vм	ODE1 = 1.8	V
Enable Current	-	0.05	0.1	mA	through Venable pin			
BATT Current	-	3	5.5	mA	through VBATT pin, VMODE1 = +1.8 V		3 V	
Leakage Current	-	<5	10	μA	VBATT = +4.4 V, VCC = +4.4 V VENABLE = 0 V, VMODE1 = 0 V			
Noise in Receive Band (2)	-	TBD	-	dBm/Hz	791 - 821 MF	łz		
Harmonics 2fo 3fo, 4fo	- -	TBD TBD	-	dBc	Роит ≤ +27.7	dBm		
Input Impedance	-	-	2:1	VSWR				
Coupling Factor	-	20	-	dB				
Directivity	-	20	-	dB				
Coupler IN-OUT Daisy Chain Insertion Loss	-	<0.25	-	dB	698 to 2620 Pin 8 to 6 Shutdown Mo			
Spurious Output Level (all suprious outputs)	-	-	<-65	<-65 dBc $Pout ≤ +27.7 dBm$ In-band load VSWR < 5:1 Out-of-band load VSWR < 10:1 Applies over all operating condition		tions		
Load mismatch stress with no permanent degradation or failure	8:1	-	-	VSWR	Applies over	full opera	ting range	Э

Notes:

(1) ACLR and Efficiency measured at 847 MHz.

APPLICATION INFORMATION

To ensure proper performance, refer to all related Application Notes on the ANADIGICS web site: http://www.anadigics.com

Shutdown Mode

The power amplifier may be placed in a shutdown mode by applying logic low levels (see Operating Ranges table) to the Venable and Vmode voltages.

Bias Modes

The power amplifier may be placed in either a Low, Medium or High Bias mode by applying the appropriate logic level (see Operating Ranges table) to VMODE1,2. The Bias Control table lists the recommended modes of operation for various applications.

Three operating modes are available to optimize current consumption. High Bias/High Power operating mode is for PouT levels \geq 15 dBm. At around 16 dBm output power, the PA should be "Mode Switched" to Medium power mode for lowest quiescent current consumption. The PA should be switched to Low Bias/Low Power mode at ~<7 dbm.

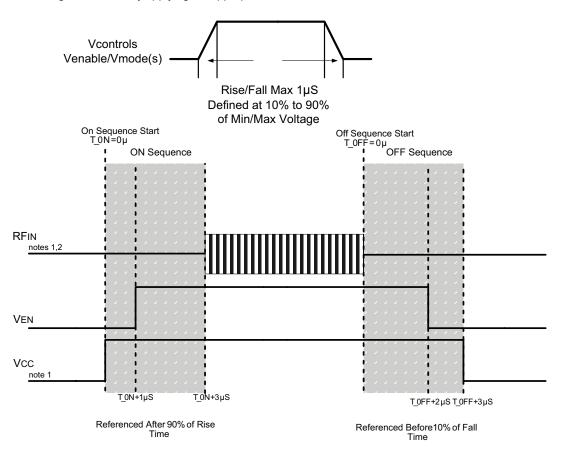


Figure 3: Recommended ON/OFF Timing Sequence

Notes:

- (1) Level might be changed after RF is ON.
- (2) RF OFF defined as P_{IN} ≤ -30 dBm.
- (3) Switching simultaneously between VMODE and VEN is not recommended.

Table 5: Bias Control

APPLICATION	Pout LEVELS	BIAS MODE	VENABLE	VMODE1	VMODE2	Vcc	V BATT
High power (High Bias Mode)	> +16 dBm	High	+1.8 V	0 V	0 V	0.6 - 4.4 V	3.1 - 4.4 V
Med power (Med Bias Mode)	≤ +17 dBm	Medium	+1.8 V	+1.8 V	0 V	0.6 - 4.4 V	3.1 - 4.4 V
Low power (Low Bias Mode)	≤ +8 dBm	Low	+1.8 V	+1.8 V	+1.8 V	0.6 - 4.4 V	3.1 - 4.4 V
Shutdown	-	Shutdown	0 V	0 V	0 V	0.6 - 4.4 V	3.1 - 4.4 V

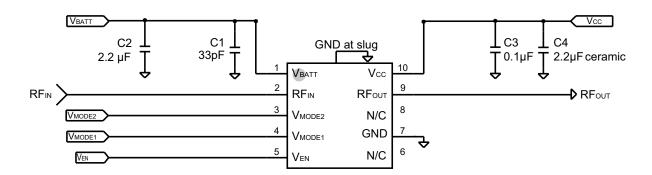
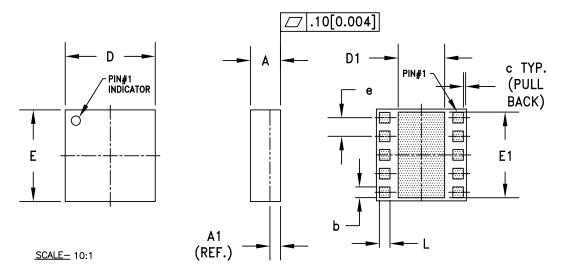


Figure 4: Evaluation Board Schematic

PACKAGE OUTLINE



S _{YMBOL}	MILLIMETERS				NOTE					
٥	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.				
Α	0.88	0.94	1.00	0.035	0.037	0.039	-			
A1		PLEASE REFER TO LAMINATE CONTROL DRAWING								
ь	0.32	0.35	0.40	0.013	0.014	0.016	3			
С	-	0.10	-	-	0.004	-	_			
D	2.88	3.00	3.12	0.113	0.118	0.123	-			
D1	1.45	1.50	1.57	0.057	0.059	0.062	3			
Ε	2.88	3.00	3.12	0.113	0.118	0.123	_			
E1	2.70	2.75	2.85	0.106	0.108	0.112	3			
е		0.60			0.024					
L	0.32	0.35	0.40	0.013	0.014	0.016	3			

NOTES:

- 1. CONTROLLING DIMENSIONS IN MILLIMETERS.
 2. UNLESS SPECIFIED, TOLERANCE=±0.076[0.003].
 3. SIGNAL PADS SHOWN UNIFORM
 SIZE FOR REFERENCE ONLY.
 ACTUAL SIZE AND LOCATION WILL
 VARY WITHIN MIN. AND MAX. DIMENSIONS
 ACCORDING TO THE PRODUCT DESIGN.
 4. GROUND PADS SHOWN UNIFORM
 SIZE FOR REFERENCE ONLY.
 ACTUAL SIZE AND LOCATION APE REFERENCE ON.
- ACTUAL SIZE AND LOCATION ARE REFERENCE ONLY.
- 5. PITCH MEASUREMENTS (e) TAKE CENTERLINE TO CENTERLINE OF SOLDERMASK OPENINGS.
 6. UNLESS SPECIFIED DIMENSIONS ARE SYMMETRICAL ABOUT CENTER LINES SHOWN.
- 7. LAMINATE CONTROL DRAWING SPECIFIED BY

Figure 5: Package Outline - 10 Pin 3 mm x 3 mm x 0.94 mm Surface Mount Module

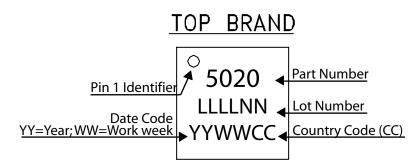
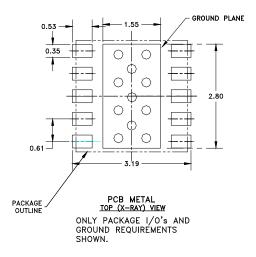


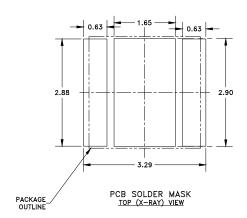
Figure 6: Branding Specification

PCB AND STENCIL DESIGN GUIDELINE



NOTES:

- (1) OUTLINE DRAWING REFERENCE: P8002478_E
- (2) UNLESS SPECIFIED DIMENSIONS
 ARE SYMMETRICAL ABOUT CENTER
 LINES SHOWN.
- (3) DIMENSIONS IN MILLIMETERS.
- (4) VIAS SHOWN IN PCB METAL VIEW ARE FOR REFERENCE ONLY.
 NUMBER & SIZE OF THERMAL VIAS REQUIRED DEPENDENT ON HEAT DISSIPATION REQUIREMENT AND THE PCB PROCESS CAPABILITY.
- (5) RECOMMENDED STENCIL THICKNESS: APPROX. 0.150mm (6 Mils)



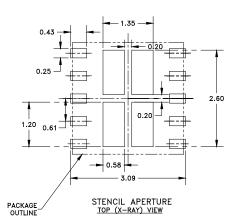
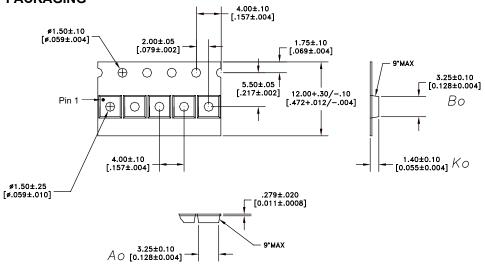


Figure 7: Recommended PCB Layout Information

COMPONENT PACKAGING



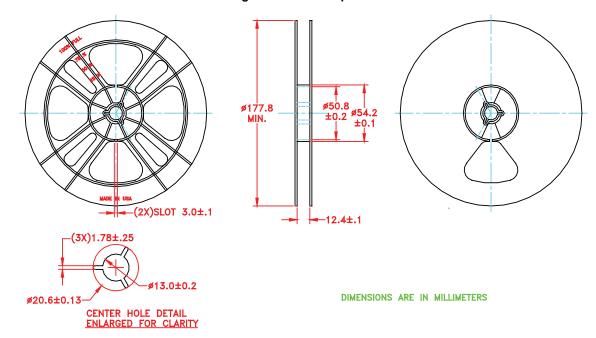
NOTES:

DIMENSIONS ARE IN MILLIMETERS [INCHES]

1. MATERIAL: 3000 (CARBON FILLED POLYCARBONATE) 100% RECYCLABLE.

DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994

Figure 8: Carrier Tape



NOTES:

1. MATERIAL: BLACI
SURFACE RESISTIVITY: 1X10

BLACK CARBON POLYSTYRENE 1X10⁴TO 1X10⁸ ohms/square

DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994

Figure 9: Reel

ALT5020

ORDERING INFORMATION

ORDER NUMBER TEMPERATURE RANGE		PACKAGE DESCRIPTION	COMPONENT PACKAGING	
ALT5020Q7	-30 °C to +90 °C	RoHS Compliant 10 Pin 3 mm x 3 mm x 0.94 mm Surface Mount Module	Tape and Reel, 2500 pieces per Reel	
ALT5020P9	-30 °C to +90 °C	RoHS Compliant 10 Pin 3 mm x 3 mm x 0.94 mm Surface Mount Module	Partial Tape and Reel	



ANADIGICS, Inc.

141 Mount Bethel Road Warren, New Jersey 07059, U.S.A.

Tel: +1 (908) 668-5000 Fax: +1 (908) 668-5132

URL: http://www.anadigics.com

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